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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

2000	
Product Status	Active
Core Processor	HCS12
Core Size	16-Bit
Speed	50MHz
Connectivity	CANbus, I ² C, SCI, SPI
Peripherals	PWM, WDT
Number of I/O	59
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	2.35V ~ 5.25V
Data Converters	A/D 16x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	80-QFP
Supplier Device Package	80-QFP (14x14)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mc9s12d64vfu

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Version Number	Revision Date	Effective Date	Author	Description of Changes
V01.15	22 July 2003	22 July 2003		Mentioned "S12 LRAE" bootloader in Flash section Section Document References: corrected S12 CPU document reference
V01.16	24 Feb. 2004	24 Feb. 2004		Added 3L86D maskset with corresponding Part ID Table Oscillator Characteristics: Added more details for EXTAL pin
V01.17	21 May 2004	21 May 2004		Added 4L86D maskset with corresponding Part ID Table "MC9S12DJ64 Memory Map out of Reset": corrected \$1000 - \$3fff memory in single chip modes to "unimplemented".
V01.18	13 July 2004	13 July 2004		Added MC9S12D32 and MC9S12A32
V01.19	2 Sept. 2004	2 Sept. 2004		Appendix, Table "Oscillator Characteristics": changed item 13 VIH,EXTAL min value from 0.7*VDDPLL to 0.75*VDDPLL item 14 VIL,EXTAL max value from 0.3*VDDPLL to 0.25*VDDPLL
V01.20	6 April 2005	6 April 2005		Table "Assigned Part ID Numbers": added mask set number0M89CTable "NVM Reliability Characteristics": added footnote concerningdata retention

Derivative Differences and Document References

Derivative Differences

Table 0-1 shows the availability of peripheral modules on the various derivatives. For details about the compatibility within the MC9S12D-Family refer also to engineering bulletin EB386.

Generic device	MC9S12DJ64	MC9S12D64	MC9S12A64	MC9S12D32	MC9S12A32
CAN0	1	1	0	1	0
J1850/BDLC	1	0	0	0	0
Packages	112LQFP, 80QFP	112LQFP, 80QFP	112LQFP, 80QFP	80QFP	80QFP
Mask Set	L86D	L86D	L86D	L86D	L86D
Temp Options	M, V, C	M, V, C	С	M, V, C	С
Package Codes	PV, FU	PV, FU	PV, FU	FU	FU
Note	An errata exists contact Sales office				

Table 0-1 Derivative Differences

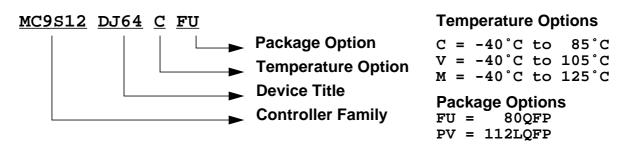


Figure 0-1 Order Partnumber Example

The following items should be considered when using a derivative.

- Registers
 - Do not write or read CAN0 registers (after reset: address range \$0140 \$017F), if using a derivative without CAN0 (see **Table 0-1**).
 - Do not write or read BDLC registers (after reset: address range \$00E8 \$00EF), if using a derivative without BDLC (see **Table 0-1**).
- Interrupts
 - Fill the four CAN0 interrupt vectors (\$FFB0 \$FFB7) according to your coding policies for unused interrupts, if using a derivative without CAN0 (see **Table 0-1**).
 - Fill the BDLC interrupt vector (\$FFC2, \$FFC3) according to your coding policies for unused interrupts, if using a derivative without BDLC (see **Table 0-1**).

MC9S12DJ64 Device User Guide — V01.20

1.4 Block Diagram

Figure 1-1 shows a block diagram of the MC9S12DJ64 device.



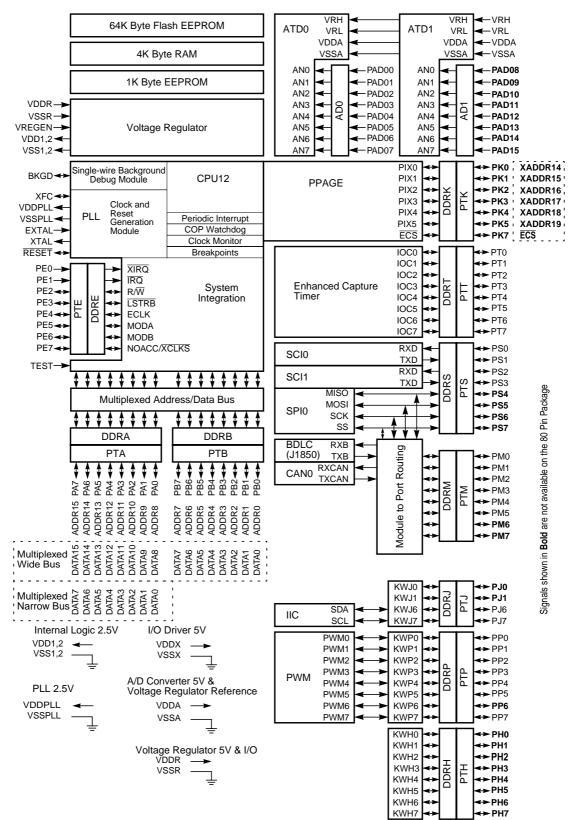


Figure 1-1 MC9S12DJ64 Block Diagram



\$00A0 - \$00C7 PW

PWM (Pulse Width Modulator 8 Bit 8 Channel)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00C2	PWMDTY6	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00C3	PWMDTY7	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
¢0004				PWMIE		PWMLVL	0	PWM7IN	PWM7INL	PWM7ENA
\$00C4	PWMSDN	Write:	PWMIF	PVVIVIE	PWMRSTRT	PVVIVILVL			PVVIVI/INL	PVVIVI/EINA
¢00CF	Decented	Read:	0	0	0	0	0	0	0	0
\$00C5	Reserved	Write:								
¢0000	Decented	Read:	0	0	0	0	0	0	0	0
\$00C6 Reserved		Write:								
¢0007		Read:	0	0	0	0	0	0	0	0
\$00C7 Reserved		Write:								

\$00C8 - \$00CF

SCI0 (Asynchronous Serial Interface)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00C8	SCI0BDH	Read:	0	0	0	SBR12	SBR11	SBR10	SBR9	SBR8
φ00 0 0	CONDENT	Write:				OBICIZ	OBIGH	OBICIO	OBIG	OBIG
\$00C9	SCI0BDL	Read:	SBR7	SBR6	SBR5	SBR4	SBR3	SBR2	SBR1	SBR0
		Write:	-			-			-	
\$00CA	SCI0CR1	Read:	LOOPS	SCISWAI	RSRC	М	WAKE	ILT	PE	PT
<i>QOOOI (</i>	00100111	Write:	2001.0	00101	nono				• =	
\$00CB	SCI0CR2	Read:	TIE	TCIE	RIE	ILIE	TE	RE	RWU	SBK
WOODD	00100112	Write:		TOIL					i wo	ODIX
\$00CC	SCI0SR1	Read:	TDRE	TC	RDRF	IDLE	OR	NF	FE	PF
\$00CC	30103111	Write:								
\$00CD	SCI0SR2	Read:	0	0	0	0	0	BRK13	TXDIR	RAF
900CD	30103R2	Write:						DKKIS	IADIK	
¢00CE	SCI0DRH	Read:	R8	Т8	0	0	0	0	0	0
\$00CE	SCIUDRE	Write:		10						
\$00CF	SCI0DRL	Read:	R7	R6	R5	R4	R3	R2	R1	R0
φυυς	SCIUDRL	Write:	T7	T6	T5	T4	T3	T2	T1	T0

\$00D0 - \$00D7

SCI1 (Asynchronous Serial Interface)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00D0	SCI1BDH	Read: Write:	0	0	0	SBR12	SBR11	SBR10	SBR9	SBR8
\$00D1	SCI1BDL	Read: Write:	SBR7	SBR6	SBR5	SBR4	SBR3	SBR2	SBR1	SBR0
\$00D2	SCI1CR1	Read: Write:	LOOPS	SCISWAI	RSRC	М	WAKE	ILT	PE	PT
\$00D3	SCI1CR2	Read: Write:	TIE	TCIE	RIE	ILIE	TE	RE	RWU	SBK
\$00D4	SCI1SR1	Read: Write:	TDRE	TC	RDRF	IDLE	OR	NF	FE	PF

\$0240 - \$027F

PIM (Port Integration Module)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0263	RDRH	Read: Write:	RDRH7	RDRH6	RDRH5	RDRH4	RDRH3	RDRH2	RDRH1	RDRH0
\$0264	PERH	Read: Write:	PERH7	PERH6	PERH5	PERH4	PERH3	PERH2	PERH1	PERH0
\$0265	PPSH	Read: Write:	PPSH7	PPSH6	PPSH5	PPSH4	PPSH3	PPSH2	PPSH1	PPSH0
\$0266	PIEH	Read: Write:	PIEH7	PIEH6	PIEH5	PIEH4	PIEH3	PIEH2	PIEH1	PIEH0
\$0267	PIFH	Read: Write:	PIFH7	PIFH6	PIFH5	PIFH4	PIFH3	PIFH2	PIFH1	PIFH0
\$0268	PTJ	Read: Write:	PTJ7	PTJ6	0	0	0	0	PTJ1	PTJ0
\$0269	PTIJ	Read:	PTIJ7	PTIJ6	0	0	0	0	PTIJ1	PTIJ0
40200	1 110	Write:								
\$026A	DDRJ	Read: Write:	DDRJ7	DDRJ7	0	0	0	0	DDRJ1	DDRJ0
\$026B	RDRJ	Read: Write:	RDRJ7	RDRJ6	0	0	0	0	RDRJ1	RDRJ0
\$026C	PERJ	Read: Write:	PERJ7	PERJ6	0	0	0	0	PERJ1	PERJ0
\$026D	PPSJ	Read: Write:	PPSJ7	PPSJ6	0	0	0	0	PPSJ1	PPSJ0
\$026E	PIEJ	Read:	PIEJ7	PIEJ6	0	0	0	0	PIEJ1	PIEJ0
ΨUZUL	1120	Write:		11200						11200
\$026F	PIFJ	Read: Write:	PIFJ7	PIFJ6	0	0	0	0	PIFJ1	PIFJ0
\$0270 -	Reserved	Read:	0	0	0	0	0	0	0	0
\$027F	176961 460	Write:								

\$0280 - \$03FF

Reserved

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0280 -	Pagaruad	Read:	0	0	0	0	0	0	0	0
\$03FF	Reserved	Write:								

1.6 Part ID Assignments

The part ID is located in two 8-bit registers PARTIDH and PARTIDL (addresses \$001A and \$001B after reset). The read-only value is a unique part ID for each revision of the chip. **Table 1-4** shows the assigned part ID number.

Device	Mask Set Number	Part ID ¹
MC9S12DJ64	0L86D	\$0200
MC9S12DJ64	1L86D	\$0201
MC9S12DJ64	2L86D	\$0201 ²
MC9S12DJ64	3L86D	\$0203
MC9S12DJ64	4L86D	\$0204
MC9S12DJ64	0M89C	\$0204

Table 1-4 Assigned Part ID Numbers

NOTES:

1. The coding is as follows:

Bit 15-12: Major family identifier

Bit 11-8: Minor family identifier

Bit 7-4: Major mask set revision number including FAB transfers

Bit 3-0: Minor - non full - mask set revision

2. 1L86D is identical to 2L86D except improved ESD performance on 2L86D

The device memory sizes are located in two 8-bit registers MEMSIZ0 and MEMSIZ1 (addresses \$001C and \$001D after reset). **Table 1-5** shows the read-only values of these registers. Refer to HCS12 Module Mapping Control (MMC) Block Guide for further details.

Table 1-5 Memory size registers

Register name	Value
MEMSIZ0	\$11
MEMSIZ1	\$80

2.3 Detailed Signal Descriptions

2.3.1 EXTAL, XTAL — Oscillator Pins

EXTAL and XTAL are the crystal driver and external clock pins. On reset all the device clocks are derived from the EXTAL input frequency. XTAL is the crystal output.

2.3.2 RESET — External Reset Pin

An active low bidirectional control signal, it acts as an input to initialize the MCU to a known start-up state, and an output when an internal MCU function causes a reset.

2.3.3 TEST — Test Pin

This input only pin is reserved for test.

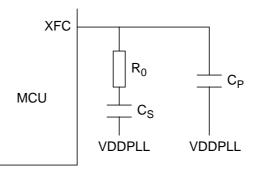
NOTE: The TEST pin must be tied to VSS in all applications.

2.3.4 VREGEN — Voltage Regulator Enable Pin

This input only pin enables or disables the on-chip voltage regulator.

2.3.5 XFC — PLL Loop Filter Pin

PLL loop filter. Please ask your Freescale representative for the interactive application note to compute PLL loop filter elements. Any current leakage on this pin must be avoided.





2.3.6 BKGD / TAGHI / MODC — Background Debug, Tag High, and Mode Pin

The BKGD/TAGHI/MODC pin is used as a pseudo-open-drain pin for the background debug communication. In MCU expanded modes of operation when instruction tagging is on, an input low on this pin during the falling edge of E-clock tags the high half of the instruction word being read into the

2.3.14 PE6 / MODB / IPIPE1 — Port E I/O Pin 6

PE6 is a general purpose input or output pin. It is used as a MCU operating mode select pin during reset. The state of this pin is latched to the MODB bit at the rising edge of $\overline{\text{RESET}}$. This pin is shared with the instruction queue tracking signal IPIPE1. This pin is an input with a pull-down device which is only active when $\overline{\text{RESET}}$ is low.

2.3.15 PE5 / MODA / IPIPE0 — Port E I/O Pin 5

PE5 is a general purpose input or output pin. It is used as a MCU operating mode select pin during reset. The state of this pin is latched to the MODA bit at the rising edge of $\overline{\text{RESET}}$. This pin is shared with the instruction queue tracking signal IPIPE0. This pin is an input with a pull-down device which is only active when $\overline{\text{RESET}}$ is low.

2.3.16 PE4 / ECLK — Port E I/O Pin 4

PE4 is a general purpose input or output pin. It can be configured to drive the internal bus clock ECLK. ECLK can be used as a timing reference.

2.3.17 PE3 / LSTRB / TAGLO — Port E I/O Pin 3

PE3 is a general purpose input or output pin. In MCU expanded modes of operation, $\overline{\text{LSTRB}}$ can be used for the low-byte strobe function to indicate the type of bus access and when instruction tagging is on, $\overline{\text{TAGLO}}$ is used to tag the low half of the instruction word being read into the instruction queue.

2.3.18 PE2 / R/W - Port E I/O Pin 2

PE2 is a general purpose input or output pin. In MCU expanded modes of operations, this pin drives the read/write output signal for the external bus. It indicates the direction of data on the external bus.

2.3.19 PE1 / IRQ — Port E Input Pin 1

PE1 is a general purpose input pin and the maskable interrupt request input that provides a means of applying asynchronous interrupt requests. This will wake up the MCU from STOP or WAIT mode.

2.3.20 PE0 / XIRQ — Port E Input Pin 0

PE0 is a general purpose input pin and the non-maskable interrupt request input that provides a means of applying asynchronous interrupt requests. This will wake up the MCU from STOP or WAIT mode.

2.3.21 PH7 / KWH7 — Port H I/O Pin 7

PH7 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.22 PH6 / KWH6 - Port H I/O Pin 6

PH6 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.23 PH5 / KWH5 — Port H I/O Pin 5

PH5 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.24 PH4 / KWH4 -- Port H I/O Pin 2

PH4 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.25 PH3 / KWH3 — Port H I/O Pin 3

PH3 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.26 PH2 / KWH2 — Port H I/O Pin 2

PH2 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.27 PH1 / KWH1 — Port H I/O Pin 1

PH1 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.28 PH0 / KWH0 — Port H I/O Pin 0

PH0 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

2.3.29 PJ7 / KWJ7 / SCL / TXCAN0 - PORT J I/O Pin 7

PJ7 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as the serial clock pin SCL of the IIC module. It can be configured as the transmit pin TXCAN of the Freescale Scalable Controller Area Network controller 0 (CAN0).

Table 4-2 Clock Selection Based on PE7

PE7 = XCLKS	Description
0	Pierce Oscillator/external clock selected

Table 4-3 Voltage Regulator VREGEN

VREGEN	Description
1	Internal Voltage Regulator enabled
0	Internal Voltage Regulator disabled, VDD1,2 and VDDPLL must be supplied externally with 2.5V

4.3 Security

The device will make available a security feature preventing the unauthorized read and write of the memory contents. This feature allows:

- Protection of the contents of FLASH,
- Protection of the contents of EEPROM,
- Operation in single-chip mode,
- Operation from external memory with internal FLASH and EEPROM disabled.

The user must be reminded that part of the security must lie with the user's code. An extreme example would be user's code that dumps the contents of the internal program. This code would defeat the purpose of security. At the same time the user may also wish to put a back door in the user's program. An example of this is the user downloads a key through the SCI which allows access to a programming routine that updates parameters stored in EEPROM.

4.3.1 Securing the Microcontroller

Once the user has programmed the FLASH and EEPROM (if desired), the part can be secured by programming the security bits located in the FLASH module. These non-volatile bits will keep the part secured through resetting the part and through powering down the part.

The security byte resides in a portion of the Flash array.

Check the Flash Block User Guide for more details on the security configuration.

4.3.2 Operation of the Secured Microcontroller

4.3.2.1 Normal Single Chip Mode

This will be the most common usage of the secured part. Everything will appear the same as if the part was not secured with the exception of BDM operation. The BDM operation will be blocked.

4.4.4 Run

Although this is not a low power mode, unused peripheral modules should not be enabled in order to save power.

Section 6 HCS12 Core Block Description

6.1 CPU12 Block Description

Consult the CPU12 Reference Manual for information on the CPU.

6.1.1 Device-specific information

When the CPU12 Reference Manual refers to *cycles* this is equivalent to *Bus Clock periods*. So *1 cycle* is equivalent to *1 Bus Clock period*.

6.2 HCS12 Module Mapping Control (MMC) Block Description

Consult the MMC Block Guide for information on the HCS12 Module Mapping Control module.

6.2.1 Device-specific information

- INITEE
 - Reset state: \$01
 - Bits EE11-EE15 are "Write once in Normal and Emulation modes and write anytime in Special modes".
- PPAGE
 - Reset state: \$00
 - Register is "Write anytime in all modes"
- MEMSIZ0
 - Reset state: \$11
- MEMSIZ1
 - Reset state: \$80

6.3 HCS12 Multiplexed External Bus Interface (MEBI) Block Description

Consult the MEBI Block Guide for information on HCS12 Multiplexed External Bus Interface module.

6.3.1 Device-specific information

- PUCR
 - Reset state: \$90

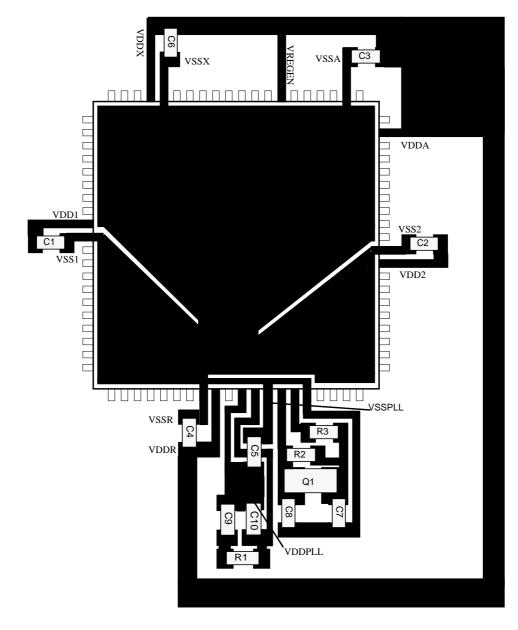


Figure 22-4 Recommended PCB Layout for 80QFP Pierce Oscillator

NOTE: Please refer to the temperature rating of the device (C, V, M) with regards to the ambient temperature T_A and the junction temperature T_J . For power dissipation calculations refer to Section A.1.8 Power Dissipation and Thermal Characteristics.

Rating	Symbol	Min	Тур	Max	Unit
I/O, Regulator and Analog Supply Voltage	V _{DD5}	4.5	5	5.25	V
Digital Logic Supply Voltage ¹	V _{DD}	2.35	2.5	2.75	V
PLL Supply Voltage ¹	V _{DDPLL}	2.35	2.5	2.75	V
Voltage Difference VDDX to VDDR and VDDA	Δ_{VDDX}	-0.1	0	0.1	V
Voltage Difference VSSX to VSSR and VSSA	Δ_{VSSX}	-0.1	0	0.1	V
Oscillator	f _{osc}	0.5	-	16	MHz
Bus Frequency	f _{bus}	0.25 ²	-	25	MHz
MC9S12DJ64 C					
Operating Junction Temperature Range	Т _Ј	-40	-	100	°C
Operating Ambient Temperature Range ³	T _A	-40	27	85	°C
MC9S12DJ64V					
Operating Junction Temperature Range	Т _Ј	-40	-	120	°C
Operating Ambient Temperature Range ³	T _A	-40	27	105	°C
MC9S12DJ64 M					
Operating Junction Temperature Range	Т _Ј	-40	-	140	°C
Operating Ambient Temperature Range ³	T _A	-40	27	125	°C

Table A-4 Operating Conditions

NOTES:

1. The device contains an internal voltage regulator to generate the logic and PLL supply out of the I/O supply. The given operating range applies when this regulator is disabled and the device is powered from an external source.

2. Some blocks e.g. ATD (conversion) and NVMs (program/erase) require higher bus frequencies for proper operation.

3. Please refer to **Section A.1.8 Power Dissipation and Thermal Characteristics** for more details about the relation between ambient temperature T_A and device junction temperature T_J.

A.1.8 Power Dissipation and Thermal Characteristics

Power dissipation and thermal characteristics are closely related. The user must assure that the maximum operating junction temperature is not exceeded. The average chip-junction temperature (T_J) in °C can be obtained from:

$$\mathsf{T}_{\mathsf{J}} = \mathsf{T}_{\mathsf{A}} + (\mathsf{P}_{\mathsf{D}} \bullet \Theta_{\mathsf{J}} \mathsf{A})$$

 T_{I} = Junction Temperature, [°C]

 T_{Δ} = Ambient Temperature, [°C]

 P_{D} = Total Chip Power Dissipation, [W]

$$\Theta_{JA}$$
 = Package Thermal Resistance, [°C/W]

The total power dissipation can be calculated from:

P_{INT} = Chip Internal Power Dissipation, [W]

Two cases with internal voltage regulator enabled and disabled must be considered:

1. Internal Voltage Regulator disabled

$$P_{INT} = I_{DD} \cdot V_{DD} + I_{DDPLL} \cdot V_{DDPLL} + I_{DDA} \cdot V_{DDA}$$
$$P_{IO} = \sum_{i} R_{DSON} \cdot I_{IO}^{2}_{i}$$

 $P_{\rm IO}$ is the sum of all output currents on I/O ports associated with VDDX and VDDR.

For R_{DSON} is valid:

$$R_{DSON} = \frac{V_{OL}}{I_{OL}}$$
; for outputs driven low

respectively

$$R_{DSON} = \frac{V_{DD5} - V_{OH}}{I_{OH}}$$
; for outputs driven high

2. Internal voltage regulator enabled

$$P_{INT} = I_{DDR} \cdot V_{DDR} + I_{DDA} \cdot V_{DDA}$$

 I_{DDR} is the current shown in **Table A-7** and not the overall current flowing into VDDR, which additionally contains the current flowing into the external loads with output high.

$$P_{IO} = \sum_{i} R_{DSON} \cdot I_{IO_{i}}^{2}$$

 P_{IO} is the sum of all output currents on I/O ports associated with VDDX and VDDR.

A.2 ATD Characteristics

This section describes the characteristics of the analog to digital converter.

A.2.1 ATD Operating Characteristics

The **Table A-8** shows conditions under which the ATD operates.

The following constraints exist to obtain full-scale, full range results:

 $V_{SSA} \le V_{RL} \le V_{IN} \le V_{RH} \le V_{DDA}$. This constraint exists since the sample buffer amplifier can not drive beyond the power supply levels that it ties to. If the input level goes outside of this range it will effectively be clipped.

Conditions are shown in Table A-4 unless otherwise noted							
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	D	Reference Potential Low High	V _{RL} V _{RH}	V _{SSA} V _{DDA} /2		V _{DDA} /2 V _{DDA}	V V
2	С	Differential Reference Voltage ¹	$V_{RH}-V_{RL}$	4.50	5.00	5.25	V
3	D	ATD Clock Frequency	f _{ATDCLK}	0.5		2.0	MHz
4	D	ATD 10-Bit Conversion Period Clock Cycles ² Conv, Time at 2.0MHz ATD Clock f _{ATDCLK}		14 7		28 14	Cycles μs
5	D	ATD 8-Bit Conversion Period Clock Cycles ² Conv, Time at 2.0MHz ATD Clock f _{ATDCLK}	N _{CONV8} T _{CONV8}	12 6		26 13	Cycles μs
6	D	Recovery Time (V _{DDA} =5.0 Volts)	t _{REC}			20	μs
7	Р	Reference Supply current 2 ATD blocks on	I _{REF}			0.750	mA
8	Ρ	Reference Supply current 1 ATD block on	I _{REF}			0.375	mA

Table A-8	ATD	Operating	Characteristics
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NOTES:

1. Full accuracy is not guaranteed when differential voltage is less than 4.50V

2. The minimum time assumes a final sample period of 2 ATD clocks cycles while the maximum time assumes a final sample period of 16 ATD clocks.

A.2.2 Factors influencing accuracy

Three factors - source resistance, source capacitance and current injection - have an influence on the accuracy of the ATD.

A.2.2.1 Source Resistance:

Due to the input pin leakage current as specified in **Table A-6** in conjunction with the source resistance there will be a voltage drop from the signal source to the ATD input. The maximum source resistance R_S

$$t_{era} \approx 4000 \cdot \frac{1}{f_{NVMOP}}$$

The setup time can be ignored for this operation.

A.3.1.4 Mass Erase

Erasing a NVM block takes:

$$t_{mass} \approx 20000 \cdot \frac{1}{f_{NVMOP}}$$

The setup time can be ignored for this operation.

A.3.1.5 Blank Check

The time it takes to perform a blank check on the Flash or EEPROM is dependent on the location of the first non-blank word starting at relative address zero. It takes one bus cycle per word to verify plus a setup of the command.

$$t_{check} \approx location \cdot t_{cyc} + 10 \cdot t_{cyc}$$

Conditions are shown in Table A-4 unless otherwise noted								
Num	С	Rating	Symbol	Min	Тур	Max	Unit	
1	D	External Oscillator Clock	f _{NVMOSC}	0.5		50 ¹	MHz	
2	D	Bus frequency for Programming or Erase Operations	f _{NVMBUS}	1			MHz	
3	D	Operating Frequency	f _{NVMOP}	150		200	kHz	
4	Ρ	Single Word Programming Time	t _{swpgm}	46 ²		74.5 ³	μs	
5	D	Flash Burst Programming consecutive word ⁴	t _{bwpgm}	20.4 ²		31 ³	μs	
6	D	Flash Burst Programming Time for 32 Words ⁴	t _{brpgm}	678.4 ²		1035.5 ³	μs	
7	Ρ	Sector Erase Time	t _{era}	20 ⁵		26.7 ³	ms	
8	Ρ	Mass Erase Time	t _{mass}	100 ⁵		133 ³	ms	
9	D	Blank Check Time Flash per block	t _{check}	11 ⁶		32778 ⁷	t _{cyc}	
10	D	Blank Check Time EEPROM per block	t _{check}	11 ⁶		2058 ⁷	t _{cyc}	

Table A-11 NVM Timing Characteristics

NOTES:

1. Restrictions for oscillator in crystal mode apply!

2. Minimum Programming times are achieved under maximum NVM operating frequency f_{NVMOP} and maximum bus frequency f_{bus}.

 Maximum Erase and Programming times are achieved under particular combinations of f_{NVMOP} and bus frequency f_{bus}. Refer to formulae in Sections A.3.1.1 - A.3.1.4 for guidance.

4. Burst Programming operations are not applicable to EEPROM

5. Minimum Erase times are achieved under maximum NVM operating frequency f_{NVMOP}.

6. Minimum time, if first word in the array is not blank

7. Maximum time to complete check on an erased block

